Linearity and enhanced sensitivity of the Shipley AZ-1350B photoresist

A. C. Livanos, A. Katzir, J. B. Shellan, and A. Yariv

The properties of the Shipley AZ-1350B positive photoresist used with the Shipley AZ-303A developer were investigated. It was found that the use of AZ-303A developer results in a significant improvement of the sensitivity and the linearity of the photoresist. The unexposed etch rate of the photoresist was $35 \pm 5 \text{ Å/sec}$. Gratings of high efficiency have been successfully fabricated using the above combination of photoresist and developer.

Current work in integrated optics requires the fabrication of relief grating structures on photoresist and the subsequent chemical or ion beam etching through the photoresist. If the period of the grating is to be less than 0.4 μm the Shipley AZ-1350B photoresist is commonly used. The properties of this positive acting photoresist have been examined in detail and it was found that the photoresist exhibits strong nonlinearity, especially for etch depth ranging from 0.05 μm to 0.2 μm. Bartolini first showed that a different developer, namely the AZ-303A, used with the old AZ-1350 photoresist (now replaced by the 1350B) results in an unexposed resist etch rate of approximately 200 Å/sec, removes the nonlinearity, and improves the sensitivity by a factor of 2 or 3. Linearity and speed or sensitivity are always of practical interest.

Norman and Singh have studied the characteristics of the AZ-1350J resist (which has replaced the old AZ-1350H) used with the AZ-303A developer and report results similar to the ones presented in Ref. 5. It is the purpose of this paper to show that the AZ-303A developer can be used with the AZ-1350B photoresist resulting in improved sensitivity and linearity and unexposed resist etch rate of $35 \pm 5 \text{ Å/sec}$.

Bartolini has shown that for a positive acting photoresist the following relationship exists between etch depth $d$ and exposure $E$ (in units of energy per unit area):

$$
\Delta d = T[r_1 - r_2 \exp(-cE)],
$$

where $T$ is the development time in seconds, $c$ is the exposure constant characteristic of the photoresist, $r_1$ is the rate of etching of exposed molecules, $r_2$ is the rate of etching of unexposed ones, and $\Delta r = (r_1 - r_2)$. If the term $cE$ is much less than 1, Eq. (1) can be linearized as follows:

$$
\Delta d \sim \Delta r T c E + r_2 T.
$$

In this work we determined the parameters involved in Eq. (2) for the Shipley AZ-1350B photoresist used with the AZ-303A developer.

The samples used were NO. 3010 microscope slides made by Clay Adams, which, cut in half, resulted in a size of 38 mm × 25 mm × 1 mm. The samples were cleaned according to the method presented in Ref. 8, and for some experiments the back surface was painted black with 3M Nextel 101-C10 velvet coating. The AZ-1350B photoresist was then deposited in a single layer, and after 30 sec it was spun at 3600 rpm for 30 sec. The samples were baked, next, for 30 min at 100°C.

The first experiment involved the determination of the etch rate of the unexposed resist as a function of development time for various solutions of AZ-303A developer with distilled water. For this purpose the samples were half immersed in the developer for the required time, rinsed with deionized water for 2 min, and then baked under vacuum at 100°C for 30 min. The step size was measured using a Sloan Dektat instrument, and the results are shown in Fig. 1. The 6:1 solution (four parts distilled water, 1 part AZ-303A developer) gave an acceptable etch rate of $35 \pm 5 \text{ Å/sec}$. The development time chosen for the subsequent experiment was 10 sec.

For comparison, we performed the same experiment using the Shipley MF-312 developer. This developer is free from trace-metallic elements and is commonly used in the fabrication of photoresist gratings in semiconductor substrates. Figure 2 shows the unexposed etch rate as a function of development time in minutes for the manufacturer's recommended dilution of 1:1. In
Table I. Unexposed Etch Rate for AZ Photoresists and AZ-303A Developer

<table>
<thead>
<tr>
<th>Photoresist</th>
<th>Unexposed etch rate</th>
<th>AZ-303A dilution</th>
<th>Reference</th>
</tr>
</thead>
<tbody>
<tr>
<td>AZ-1350</td>
<td>150 Å/sec</td>
<td>4:1</td>
<td>4,5</td>
</tr>
<tr>
<td>AZ-1350B</td>
<td>35 Å/sec</td>
<td>6:1</td>
<td>This paper</td>
</tr>
<tr>
<td>AZ-1350H</td>
<td>-</td>
<td>-</td>
<td>-</td>
</tr>
<tr>
<td>AZ-1350J</td>
<td>200 Å/sec</td>
<td>6:1</td>
<td>8</td>
</tr>
</tbody>
</table>

Fig. 1. Etch depths in μm of unexposed AZ-1350B photoresist as a function of development time in seconds for various dilutions ratios of AZ-303A developer. The slope of the curves determines $r_2$, which for the 6:1 dilution is $35 \pm 5$ Å.

In this case $r_2$ is $5 \pm 1$ Å/sec, which is a much lower etch rate than the one for AZ-303A developer. If resist thickness is small, if long exposure times are acceptable, and if linearity is unimportant, this may indeed be a better choice.

The results for the different resists using the different dilutions of the AZ-303A developer are given in Table I.

To demonstrate the thickness change as a function of exposure time, the 0.4416-μm line of a He–Cd laser was used to illuminate half of the sample. The back surface of the sample was coated with black paint to avoid interference fringes. The intensity distribution of the laser was better than 5% across the surface of the sample. The photoresist was exposed for a given time and then developed 10 sec in the AZ-303A developer 6:1 dilution. Figure 3 shows the thickness change as a function of exposure energy. It can be clearly seen that the behavior of the photoresist in the important 0.1–0.2-μm range is linear. In contrast, the MF-312 developer gave very small thickness changes for the same range of exposures. In order to verify that the stylus of the instrument was not scratching the surface, the same samples were aluminized and then tested.

To demonstrate the feasibility of using AZ-1350B photoresist with the AZ-303A developer in making high efficiency gratings, the following experiment was performed. Photoresist was spin-coated on samples at 3000 rpm, resulting in a resist thickness of about 3.1 μm. The gratings were generated by exposing the samples to the sinusoidal intensity distribution produced by the interference pattern of two collimated Ar+ laser beams. The wavelength used was 0.4579 μm, the angle between the beams 94.5°, and the intensity per beam 0.60 mW/cm². The exposed samples were developed in AZ-303A developer, baked under vacuum, and the efficiency of the gratings was measured. Figure 4 shows the absolute efficiency of the gratings as a function of exposure for two different development times. It is clear that high efficiency 23% resulted by developing the samples for 10 sec. To verify the theoretically predicted period and the peak to trough height, a scanning electron microscope was used. The period was measured to be 0.31 μm, and the peak to trough height was 0.28 μm.
In conclusion, we have found that the use of AZ-303A developer with the AZ-1350B photoresist results in an unexposed etch rate of ~35 Å/sec and significantly increases the sensitivity and linearity of the photoresist in the 0.05–0.2-µm range. We have successfully made gratings with constant and variable period using this method and have transferred them to glass using ion beam etching techniques.

References

Uniformly spaced color samples

The Optical Society of America announces the availability of a set of 552 uniformly spaced color samples designed by the OSA Committee on Uniform Color Scales. The colors can be arranged in hundreds of orderly sequences called color scales, most of which have never been seen previously because they cannot be constructed by use of any other set of color cards. Plans for arranging the cards in those scales will be provided.

Artists and designers have discovered that harmonious combinations result when a few colors selected from any such scale are used as elements of a design or composition. The OSA colors will reveal many new scales and suggest to creative workers, for their trial and selection, many new combinations of colors.

Although scales of constant lightness and constant hue are included, most of the scales exhibit variations of both attributes, in many different combinations. Each color card (except the darkest, or lightest, or those of highest saturation) is a member of six entirely different color scales. Most color scales do not include a neutral (black, gray, or white). For further information, see J. Opt. Soc. Am. 64, 1691 (1974).

The OSA color cards are two inches square, coated with durable, glossy automobile-finish paint on highest-quality heavy white card-stock paper. The OSA committee’s three-number color designation—lightness, yellowness, and greenness—is printed on the back of each card. Negatives as well as positive values of any or all of those numbers provide designations for all possible colors. All colors producible with durable paints are represented in the set.

The set of cards is furnished in a 3-ring hardback notebook that holds 28 flexible, transparent pages; each page contains 20 pockets, into each of which one color card is inserted. Behind each pocket page is a white-paper guide page on which the three-number designation of the appropriate color card is printed so as to be visible through any pocket from which the color card has been removed for assembly into a color scale, or for any other use. The notebook can therefore be easily restored to its original state after selected cards have been removed for use.

Sets may be ordered from the Optical Society of America, Suite 620, 2000 L Street, N.W., Washington, D.C. 20036. The price is $350. Include remittance with personal orders. A small number of sets of larger cards, without notebooks, is available on a first-come first-served basis. Some large cards have minor scratches on the surface and/or small flaws close to one edge. Prices (for complete sets only): slightly larger than 6 × 8 in. $4000; slightly larger than 4 × 6 in. $2100; slightly larger than 2 × 6 in. or 3 × 4 in., $1100.

The production of this set of colors is the culmination of 35 years of research by members of the OSA committee directed toward producing a set of samples whose color differences consist solely of chromaticity differences without luminance differences.